

FAST TRANSIENT RESPONSE, 1-A LOW-DROPOUT VOLTAGE REGULATORS

FEATURES

- **Input Voltage Range:** 2.7 V to 10 V
- **Low-Dropout Voltage:** 230 mV typical at 1 A (TPS76850)
- **2% Tolerance Over Specified Conditions for Fixed-Output Versions**
- **Open Drain Power Good (See TPS767xx for Power-On Reset With 200-ms Delay Option)**
- **Ultralow 85 μ A Typical Quiescent Current**
- **Available in 1.5-V, 1.8-V, 2.5-V, 2.7-V, 2.8-V, 3.0-V, 3.3-V, 5.0-V Fixed Output and Adjustable (1.2 V to 5.5 V) Versions**
- **Fast Transient Response**
- **Thermal Shutdown Protection**
- **SOIC-8 (D) and TSSOP-20 (PWP) Package**

DESCRIPTION

This device is designed to have a fast transient response and be stable with 10 μ F capacitors. This combination provides high performance at a reasonable cost.

Since the PMOS device behaves as a low-value resistor, the dropout voltage is very low (typically 230 mV at an output current of 1 A for the TPS76850) and is directly proportional to the output current. Additionally, because the PMOS pass element is a voltage-driven device, the quiescent current is very low and independent of output loading (typically 85 μ A over the full range of output current, 0 mA to 1 A). These two key specifications yield a significant improvement in operating life for battery-powered systems. This LDO family also features a shutdown mode; applying a TTL high signal to $\overline{\text{EN}}$ (enable) shuts down the regulator, reducing the quiescent current to less than 1 μ A at $T_j = 25^\circ\text{C}$.

Power good (PG) is an active high output, which can be used to implement a power-on reset or a low-battery indicator.

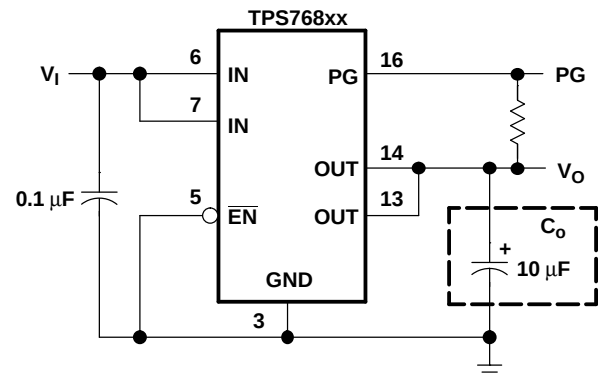
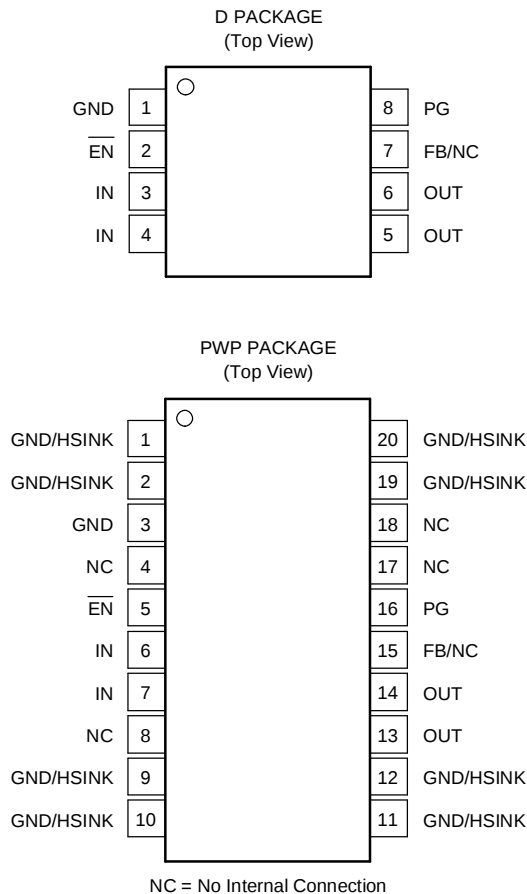


Figure 1. Typical Application Configuration (For Fixed Output Options)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION⁽¹⁾

PRODUCT	V _{OUT} ⁽²⁾
TPS768xxQyyy	XX is nominal output voltage (for example, 28 = 2.8 V, 285 = 2.85 V, 01 = Adjustable). YYY is package designator. Z is package quantity.

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
- (2) Custom output voltages are available; minimum order quantities may apply. Contact factory for details and availability.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

	VALUE
Input voltage range, V _I ⁽²⁾	–0.3 V to 13.5 V
Voltage range at $\overline{\text{EN}}$	–0.3 V to V _I + 0.3 V
Maximum PG voltage	16.5 V
Peak output current	Internally limited
Continuous total power dissipation	See Dissipation Rating Table
Output voltage, V _O (OUT, FB)	7 V
Operating junction temperature range, T _J	–40°C to +125°C
Storage temperature range, T _{stg}	–65°C to +150°C
ESD rating, HBM	2 kV

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to network terminal ground.

DISSIPATION RATING TABLE—FREE-AIR TEMPERATURES

PACKAGE	AIR FLOW (CFM)	T _A < +25°C POWER RATING	DERATING FACTOR ABOVE T _A = +25°C	T _A = +70°C POWER RATING	T _A = +85°C POWER RATING
D	0	568.18 mW	5.6818 mW/°C	312.5 mW	227.27 mW
	250	904.15 mW	9.0415 mW/°C	497.28 mW	361.66 mW
PWP ⁽¹⁾	0	3.1 W	30.7 mW/°C	1.7 W	1.2 W
	250	4.1 W	41.2 mW/°C	2.3 W	1.6 W

- (1) This parameter is measured with the recommended copper heat sink pattern on a 4-layer, 5-in × 5-in PCB, 1 oz. copper, 4-in × 4-in coverage (4 in²).

RECOMMENDED OPERATING CONDITIONS

	MIN	MAX	UNIT
Input voltage, V _I ⁽¹⁾	2.7	10	V
Output voltage range, V _O	1.2	5.5	V
Output current, I _O ⁽²⁾	0	1.0	A
Operating junction temperature, T _J ⁽²⁾	–40	+125	°C

- (1) Minimum V_{IN} = V_{OUT} + V_{DO} or 2.7 V, whichever is greater.
- (2) Continuous current and operating junction temperature are limited by internal protection circuitry, but it is not recommended that the device operate under conditions beyond those specified in this table for extended periods of time.

ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range, $V_I = V_{O(typ)} + 1\text{ V}$, $I_O = 1\text{ mA}$, $\overline{EN} = 0\text{ V}$, $C_O = 10\text{ }\mu\text{F}$ (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{OUT} Accuracy		−40°C ≤ T _J ≤ +125°C, V _O + 1 V ≤ V _{IN} ≤ 10V ⁽¹⁾ , 10 μA ≤ I _O ≤ 1A	(0.98)V _O	V _O	(1.02)V _O	V
Quiescent current (GND current) $\overline{\text{EN}} = 0\text{V}$ ⁽¹⁾		10 μA < I _O < 1 A, T _J = +25°C	85			μA
		I _O = 1 A, T _J = −40°C to +125°C	125			
Output voltage line regulation (ΔV _O /V _O) ⁽¹⁾⁽²⁾		V _O + 1 V < V _I ≤ 10 V, T _J = +25°C	0.01			%/V
Load regulation			3			mV
Output noise voltage (TPS76818)		BW = 200 Hz to 100 kHz, C _O = 10 μF, I _C = 1 A, T _J = +25°C	55			μVrms
Output current limit		V _O = 0 V	1.2	1.7	2	A
Thermal shutdown junction temperature			150			°C
Standby current		$\overline{V_{\text{EN}}} = V_{\text{I}}$, T _J = +25°C, 2.7 V < V _I < 10 V	1			μA
		$\overline{V_{\text{EN}}} = V_{\text{I}}$, T _J = −40°C to +125°C, 2.7 V < V _I < 10 V	10			μA
FB pin current, I _{FB}	TPS76801	V _{FB} = 1.5 V	2			nA
High-level enable input voltage			1.7			V
Low-level enable input voltage			0.9			V
Power-supply ripple rejection ⁽¹⁾		f = 1 kHz, C _O = 10 μF, T _J = +25°C	60			dB
Power Good (PG)	Minimum input voltage for valid PG	I _{O(PG)} = 300 μA	1.1			V
	Trip threshold voltage	V _O decreasing	92	98		%V _O
	Hysteresis voltage	Measured at V _O	0.5			%V _O
	Output low voltage	V _I = 2.7 V, I _{O(PG)} = 1 mA	0.15	0.4		V
	Leakage current	V _(PG) = 5 V	1			μA
Enable pin current (I _{EN})		$\overline{V_{\text{EN}}} = 0\text{ V}$	1	0	1	μA
		$\overline{V_{\text{EN}}} = V_{\text{I}}$	1	1		
Dropout voltage ⁽³⁾	TPS76828	I _O = 1 A, T _J = +25°C	500			mV
		I _O = 1 A, T _J = −40°C to +125°C	825			
	TPS76830	I _O = 1 A, T _J = +25°C	450			
		I _O = 1 A, T _J = −40°C to +125°C	675			
	TPS76833	I _O = 1 A, T _J = +25°C	350			
		I _O = 1 A, T _J = −40°C to +125°C	575			
TPS76850	I _O = 1 A, T _J = +25°C	230				
	I _O = 1 A, T _J = −40°C to +125°C	380				

(1) Minimum IN operating voltage is 2.7 V or $V_{O(typ)} + 1\text{ V}$, whichever is greater. Maximum IN voltage 10 V.

(2) If $V_O \leq 1.8\text{ V}$ then $V_{I_{max}} = 10\text{ V}$, $V_{I_{min}} = 2.7\text{ V}$:
$$\text{Line Reg. (mV)} = (\% / \text{V}) \times V_O \frac{(V_{I_{max}} - 2.7\text{ V})}{100} \times 1000$$

If $V_O \geq 2.5\text{ V}$ then $V_{I_{max}} = 10\text{ V}$, $V_{I_{min}} = V_O + 1\text{ V}$:
$$\text{Line Reg. (mV)} = (\% / \text{V}) \times V_O \frac{(V_{I_{max}} - (V_O + 1\text{ V}))}{100} \times 1000$$

(3) IN voltage equals $V_{O(typ)} - 100\text{ mV}$; TPS76801 output voltage set to 3.3 V nominal with external resistor divider. TPS76815, TPS76818, TPS76825, and TPS76827 dropout voltage limited by input voltage range limitations (that is, TPS76830 input voltage must drop to 2.9 V for the purpose of this test).

FUNCTIONAL BLOCK DIAGRAM—Adjustable Version



FUNCTIONAL BLOCK DIAGRAM—Fixed-Voltage Version



Terminal Functions

NAME	SOIC-8 (D) PIN NO.	TSSOP-20 (PWP) PIN NO.	DESCRIPTION
GND	1	3	Regulator ground
GND/HSINK	—	1, 2, 9-12, 19, 20	Regulator ground and heatsink
NC	—	4, 8, 17, 18	No connect
$\overline{\text{EN}}$	2	5	Enable input
IN	3, 4	6, 7	Input voltage
OUT	5, 6	13, 14	Regulated output voltage
FB/NC	7	15	Feedback input voltage for adjustable device (no connect for fixed options)
PG	8	16	PG output

TYPICAL CHARACTERISTICS

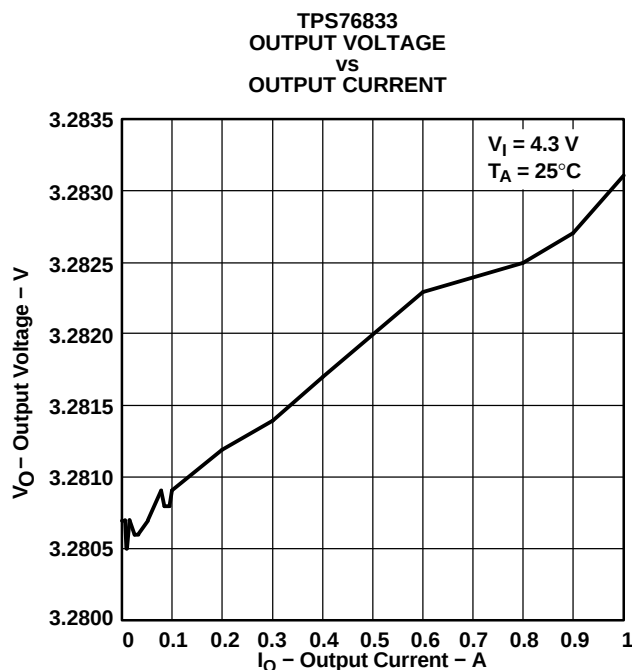


Figure 2.

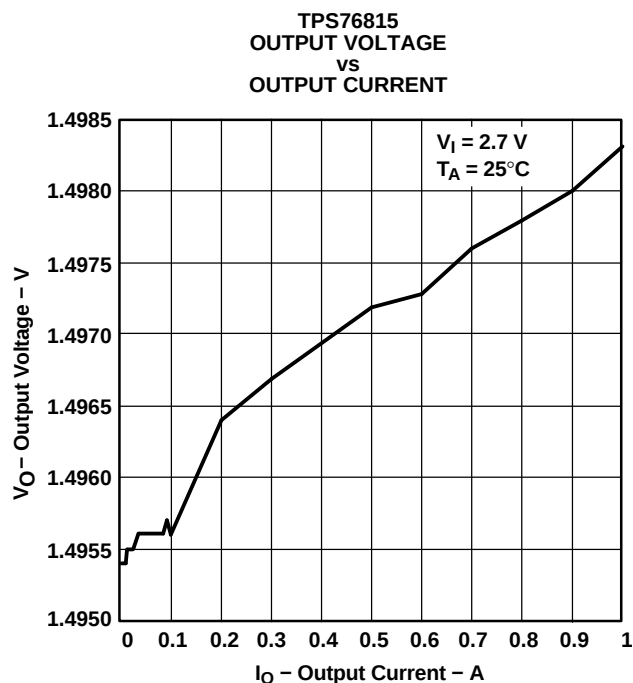


Figure 3.

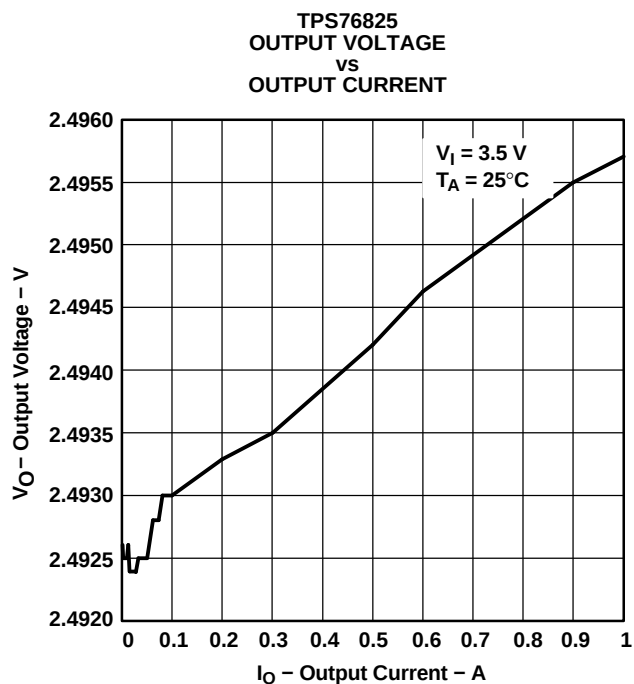


Figure 4.

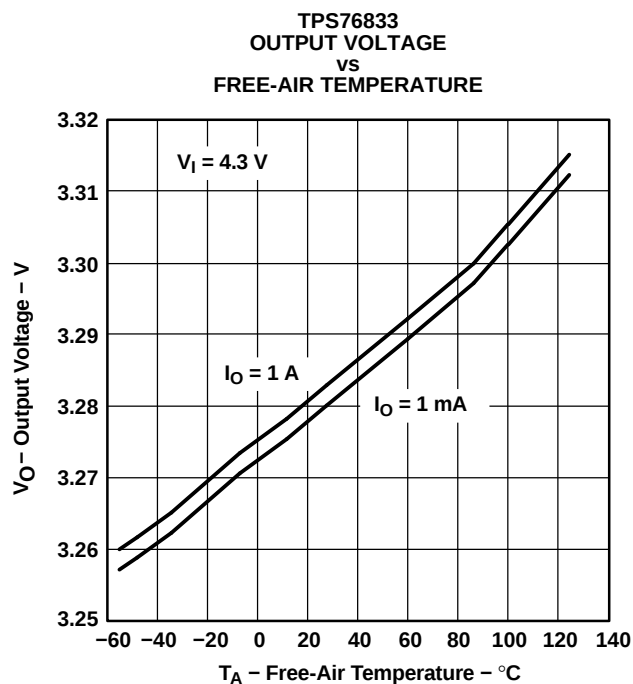


Figure 5.

TYPICAL CHARACTERISTICS (continued)

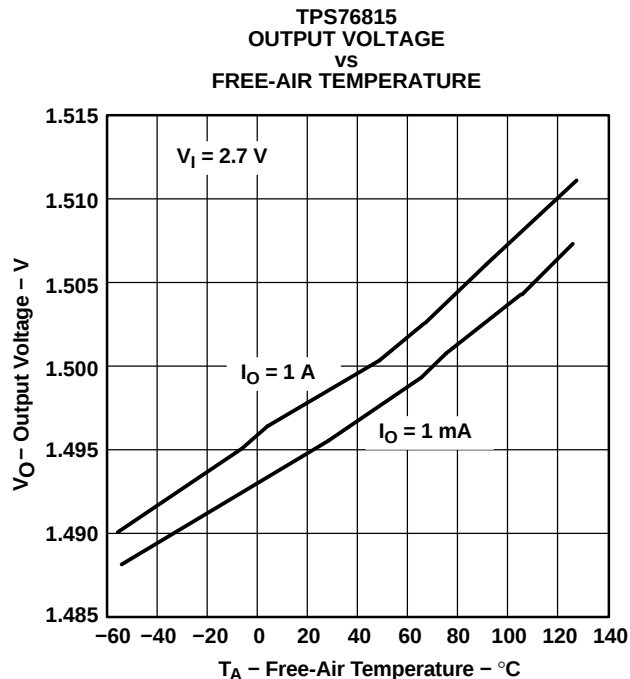


Figure 6.

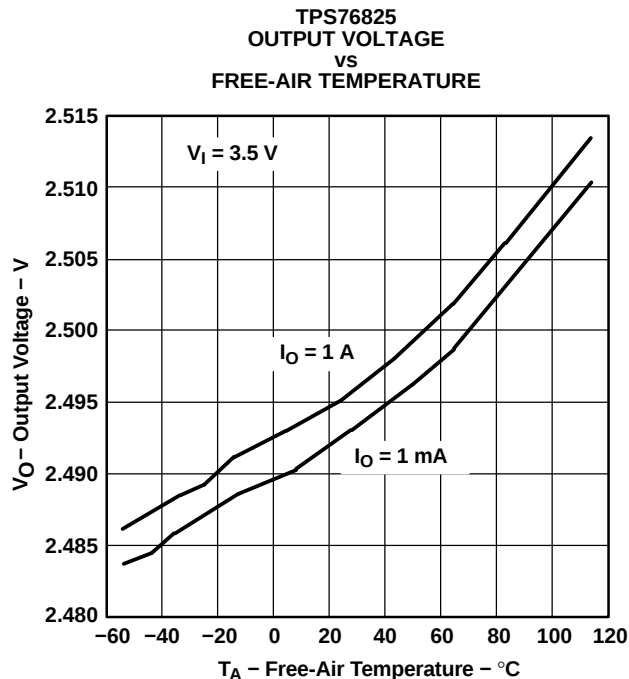


Figure 7.

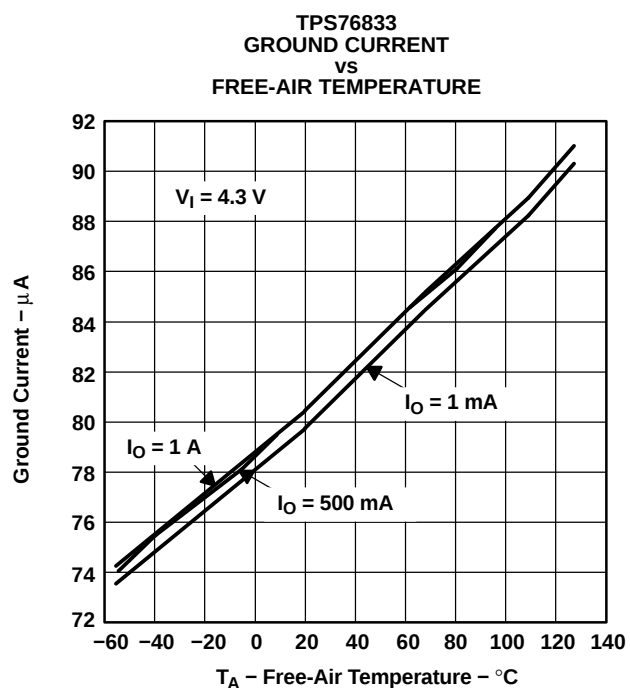


Figure 8.

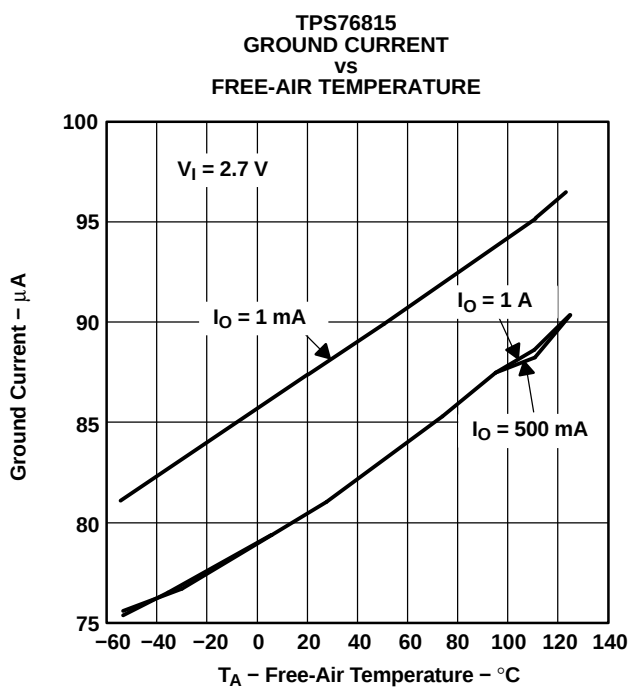


Figure 9.

TYPICAL CHARACTERISTICS (continued)

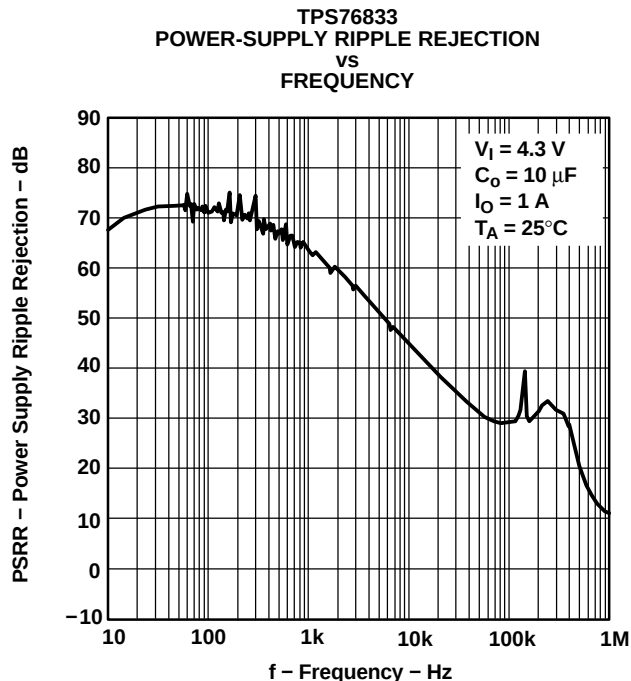


Figure 10.

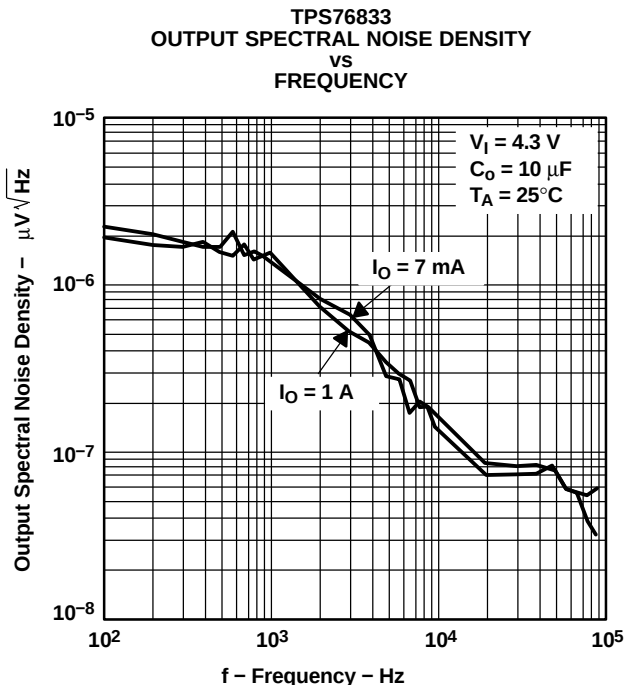


Figure 11.

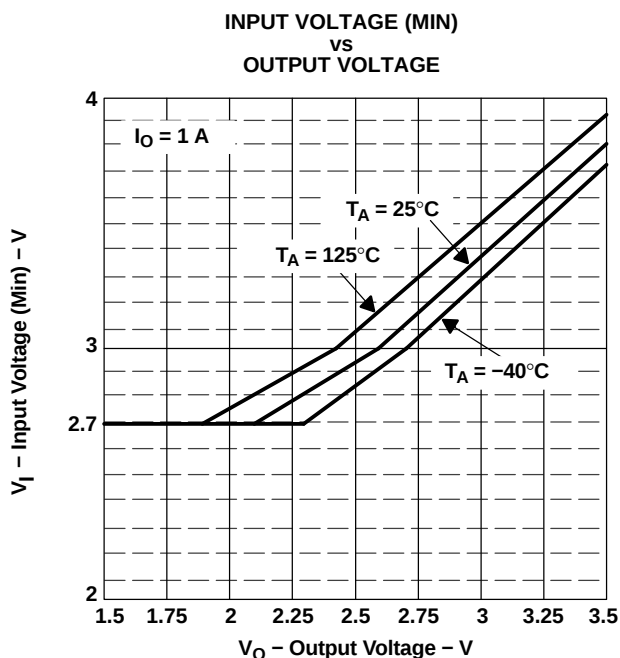


Figure 12.

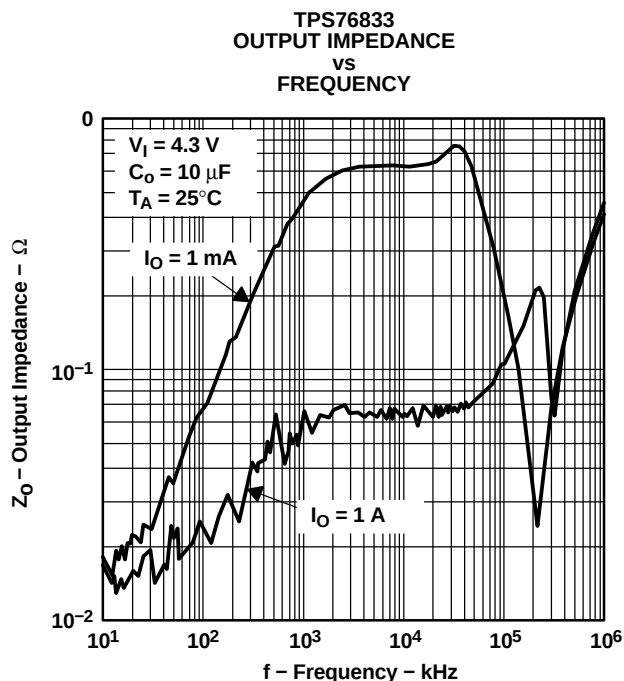


Figure 13.

TYPICAL CHARACTERISTICS (continued)

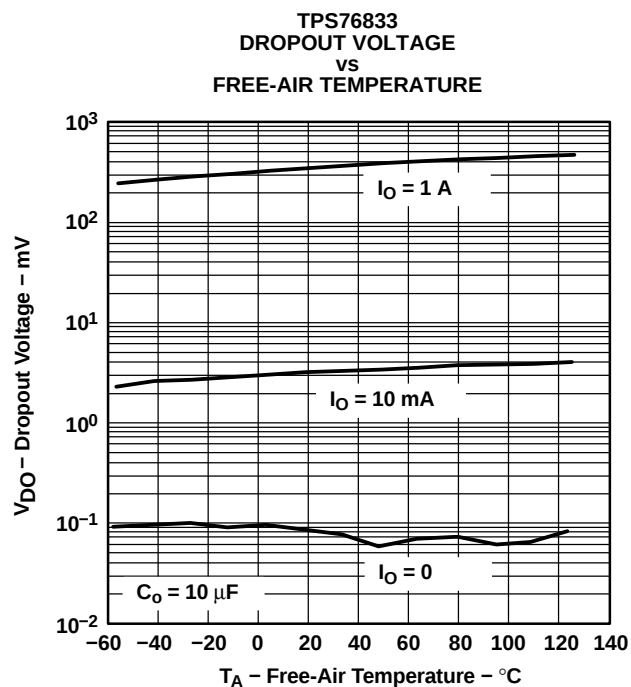


Figure 14.

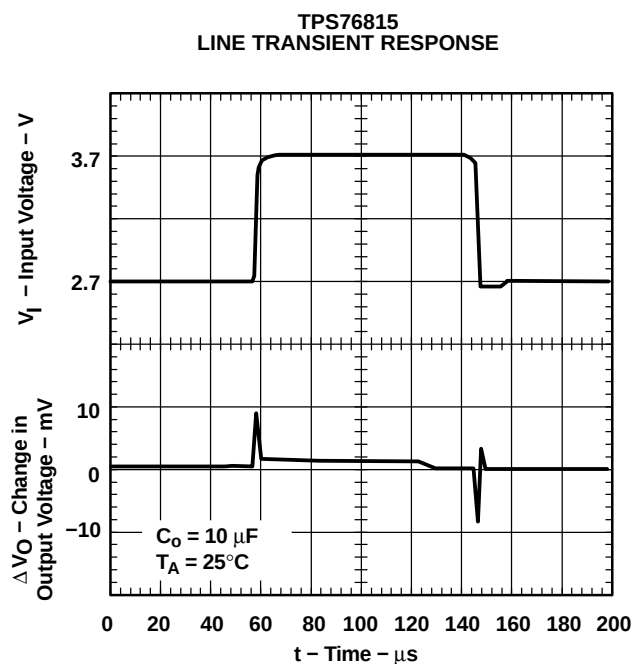


Figure 15.

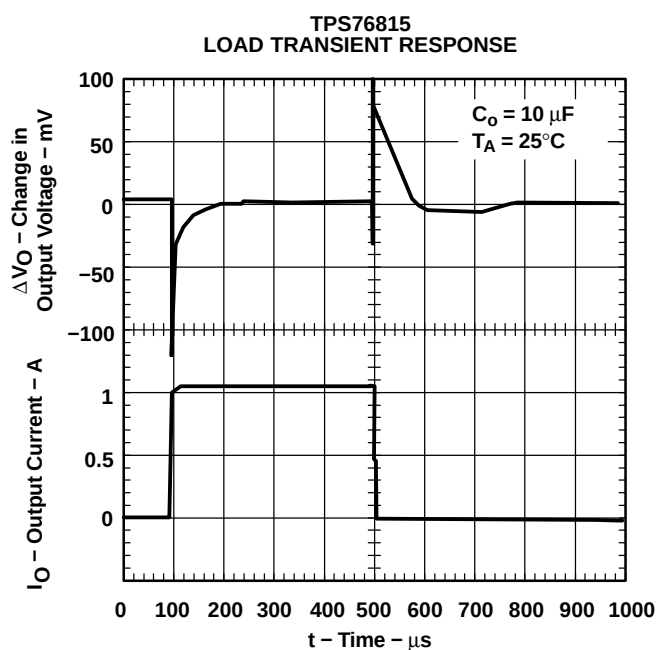


Figure 16.

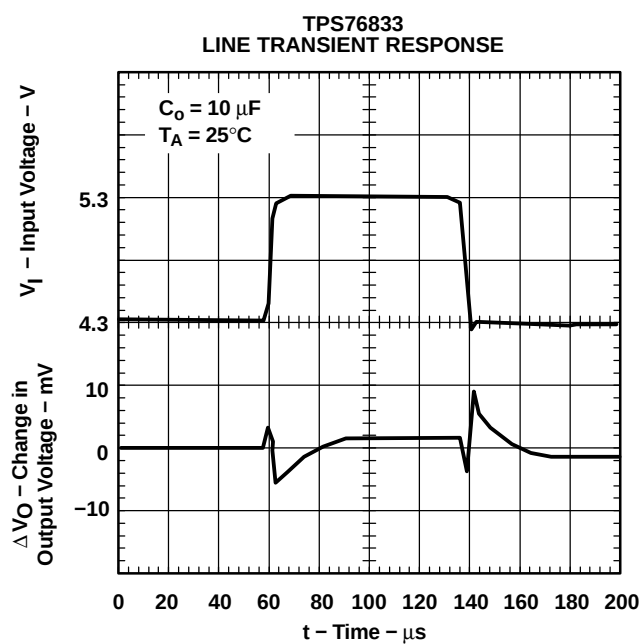


Figure 17.

TYPICAL CHARACTERISTICS (continued)

TPS76833 LOAD TRANSIENT RESPONSE

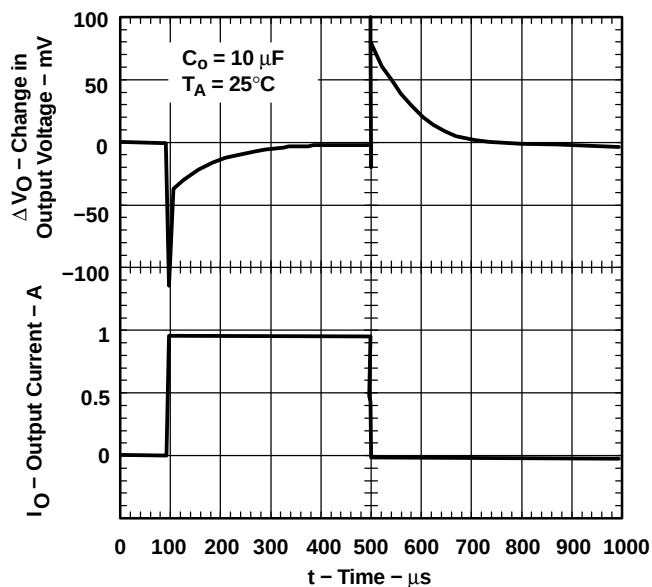


Figure 18.

**TPS76833
OUTPUT VOLTAGE
VS
TIME (AT START-UP)**

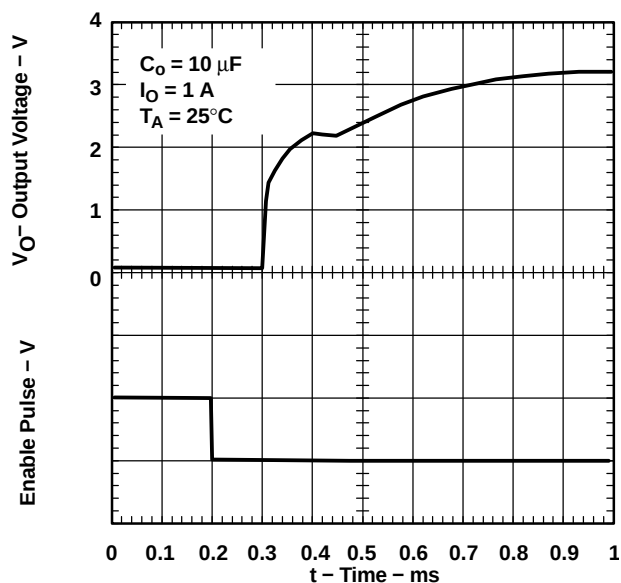


Figure 19.

TPS76801 DROPOUT VOLTAGE VS INPUT VOLTAGE

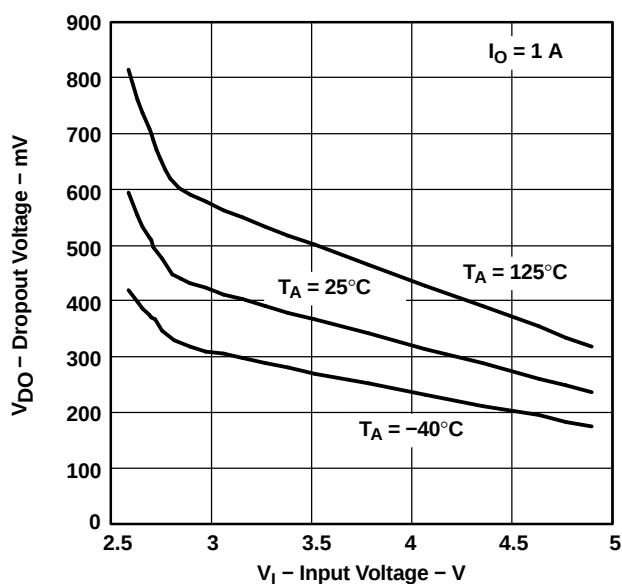


Figure 20.

TEST CIRCUIT FOR TYPICAL REGIONS OF STABILITY
(Figure 22 through Figure 25)
(Fixed Output Options)

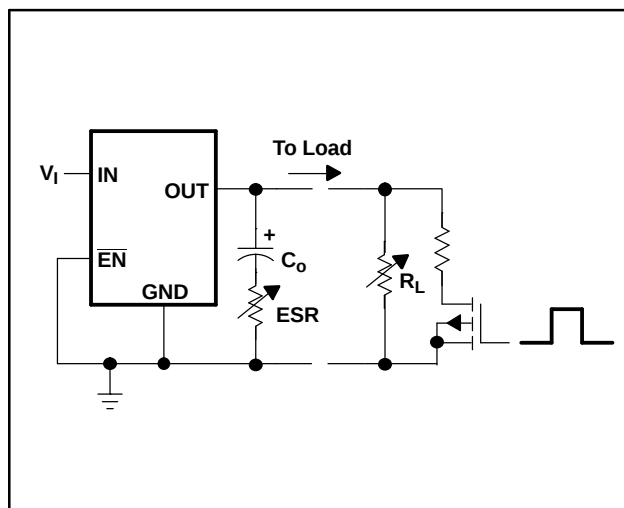


Figure 21.

TYPICAL CHARACTERISTICS (continued)

Equivalent series resistance (ESR) refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to C_O .

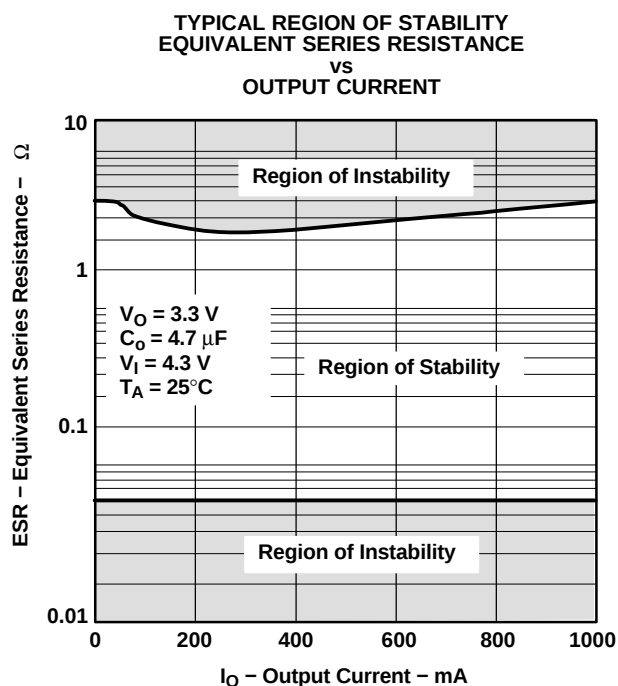


Figure 22.

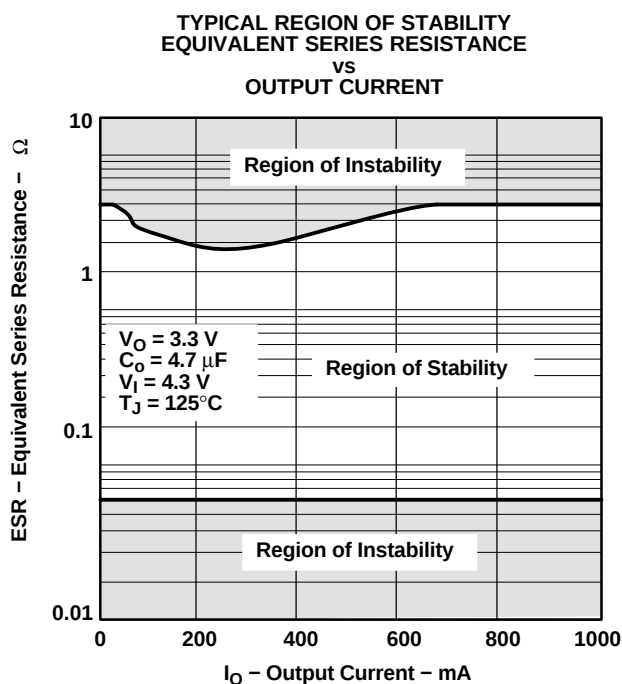


Figure 23.

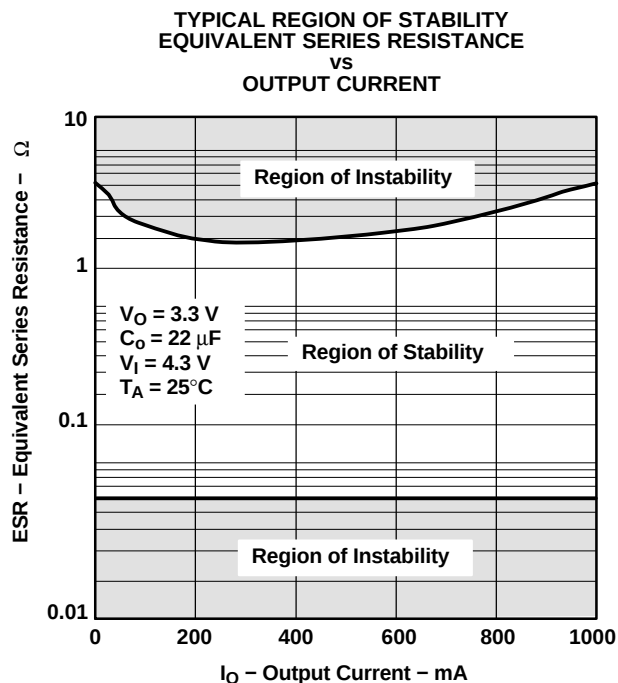


Figure 24.

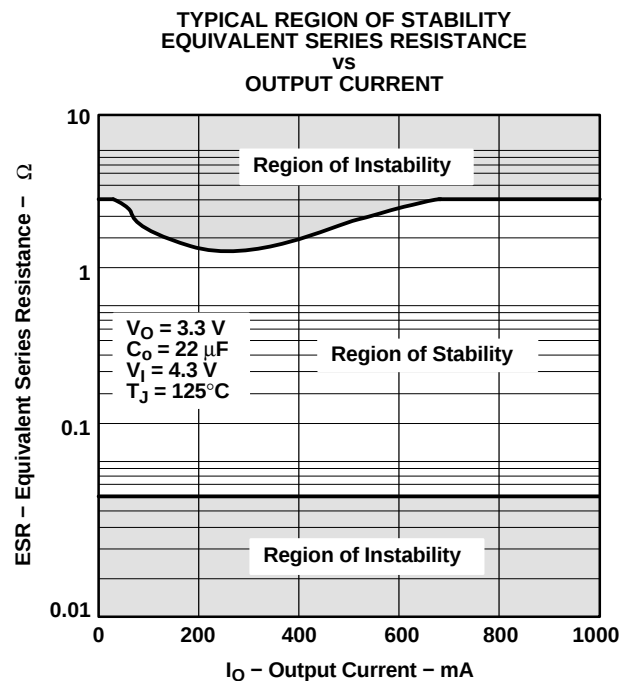


Figure 25.

APPLICATION INFORMATION

The TPS768xxQ family includes eight fixed-output voltage regulators (1.5 V, 1.8 V, 2.5 V, 2.7 V, 2.8 V, 3.0 V, 3.3 V, and 5.0 V), and offers an adjustable device, the TPS76801 (adjustable from 1.2 V to 5.5 V).

DEVICE OPERATION

The TPS768xxQ features very low quiescent current, which remains virtually constant even with varying loads. Conventional LDO regulators use a PNP pass element, the base current of which is directly proportional to the load current through the regulator ($I_B = I_C/\beta$). The TPS768xxQ uses a PMOS transistor to pass current; because the gate of the PMOS is voltage driven, operating current is low and invariable over the full load range.

Another pitfall associated with the PNP-pass element is its tendency to saturate when the device goes into dropout. The resulting drop in β forces an increase in I_B to maintain the load. During power up, this translates to large start-up currents. Systems with limited supply current may fail to start up. In battery-powered systems, it means rapid battery discharge when the voltage decays below the minimum required for regulation. The TPS768xxQ quiescent current remains low even when the regulator drops out, eliminating both problems.

The TPS768xxQ family also features a shutdown mode that places the output in the high-impedance state (essentially equal to the feedback-divider resistance) and reduces quiescent current to 2 μ A. If the shutdown feature is not used, $\overline{EN}$ should be tied to ground.

MINIMUM LOAD REQUIREMENTS

The TPS768xxQ family is stable even at zero load; no minimum load is required for operation.

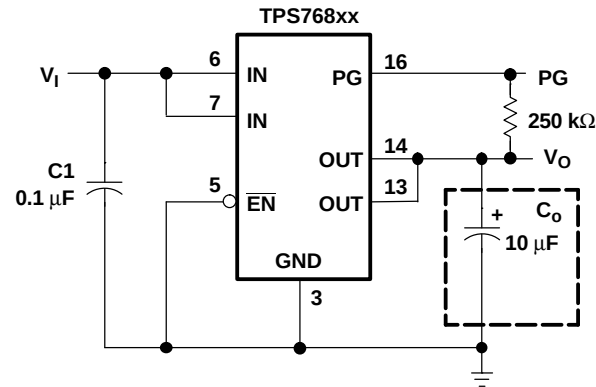
FB - PIN CONNECTION (ADJUSTABLE VERSION ONLY)

The FB pin is an input pin to sense the output voltage and close the loop for the adjustable option. The output voltage is sensed through a resistor divider network to close the loop as shown in [Figure 27](#). Normally, this connection should be as short as possible; however, the connection can be made near a critical circuit to improve performance at that point. Internally, FB connects to a high-impedance wide-bandwidth amplifier and noise pickup feeds through to the regulator output. Routing the FB connection to minimize/avoid noise pickup is essential.

EXTERNAL CAPACITOR REQUIREMENTS

An input capacitor is not usually required; however, a ceramic bypass capacitor (0.047 μ F or larger) improves load transient response and noise rejection if the TPS768xxQ is located more than a few inches from the power supply. A higher-capacitance electrolytic capacitor may be necessary if large (hundreds of milliamps) load transients with fast rise times are anticipated.

Like all low dropout regulators, the TPS768xxQ requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance value is 10 μ F and the ESR (equivalent series resistance) must be between 60 m Ω and 1.5 Ω . Capacitor values 10 μ F or larger are acceptable, provided the ESR is less than 1.5 Ω . Solid tantalum electrolytic, aluminum electrolytic, and multilayer ceramic capacitors are all suitable, provided they meet the requirements described above.

APPLICATION INFORMATION (continued)**Figure 26. Typical Application Circuit (Fixed Versions)**

The output voltage of the TPS76801 adjustable regulator is programmed using an external resistor divider as shown in [Figure 27](#). The output voltage is calculated using:

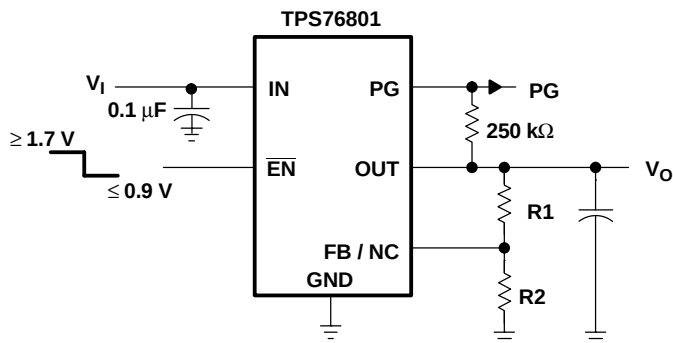
$$V_O = V_{ref} \times \left(1 + \frac{R1}{R2}\right)$$

where:

$$V_{ref} = 1.1834 \text{ V typ (the internal reference voltage)} \quad (1)$$

Resistors R1 and R2 should be chosen for approximately 50-μA divider current. Lower value resistors can be used but offer no inherent advantage and waste more power. Higher values should be avoided as leakage currents at FB increase the output voltage error. The recommended design procedure is to choose $R2 = 30.1 \text{ k}\Omega$ to set the divider current at 50 μA and then calculate R1 using:

$$R1 = \left(\frac{V_O}{V_{ref}} - 1\right) \times R2 \quad (2)$$

**OUTPUT VOLTAGE
PROGRAMMING GUIDE**

OUTPUT VOLTAGE	R1	R2	UNIT
2.5 V	33.2	30.1	kΩ
3.3 V	53.6	30.1	kΩ
3.6 V	61.9	30.1	kΩ
4.75 V	90.8	30.1	kΩ

Figure 27. TPS76801 Adjustable LDO Regulator Programming**POWER-GOOD INDICATOR**

The TPS768xxQ features a power-good (PG) output that can be used to monitor the status of the regulator. The internal comparator monitors the output voltage: when the output drops to between 92% and 98% of its nominal regulated value, the PG output transistor turns on, taking the signal low. The open-drain output requires a pullup resistor. If not used, it can be left floating. PG can be used to drive power-on reset circuitry or used as a low-battery indicator. PG does not assert itself when the regulated output voltage falls out of the specified 2% tolerance, but instead reports an output voltage low, relative to its nominal regulated value.

APPLICATION INFORMATION (continued)

REGULATOR PROTECTION

The TPS768xxQ PMOS-pass transistor has a built-in back diode that conducts reverse currents when the input voltage drops below the output voltage (for example, during power-down). Current is conducted from the output to the input and is not internally limited. When extended reverse voltage is anticipated, external limiting may be appropriate.

The TPS768xxQ also features internal current limiting and thermal protection. During normal operation, the TPS768xxQ limits output current to approximately 1.7 A. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds +150°C (typ), thermal-protection circuitry shuts it down. Once the device has cooled below +130°C (typ), regulator operation resumes.

POWER DISSIPATION AND JUNCTION TEMPERATURE

Specified regulator operation is assured to a junction temperature of +125°C; the maximum junction temperature should be restricted to +125°C under normal operating conditions. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, P_{Dmax} , and the actual dissipation, P_D , which must be less than or equal to P_{Dmax} .

The maximum-power-dissipation limit is determined using the following equation:

$$P_{Dmax} = \frac{T_{Jmax} - T_A}{R_{\theta JA}} \quad (3)$$

Where:

- T_{Jmax} is the maximum allowable junction temperature.
- $R_{\theta JA}$ is the thermal resistance junction-to-ambient for the package; that is, 172°C/W for the 8-pin SOIC (D) and 32.6°C/W for the 20-pin TSSOP (PWP) with no airflow.
- T_A is the ambient temperature.

The regulator dissipation is calculated using:

$$P_D = (V_I - V_O) \times I_O \quad (4)$$

Power dissipation resulting from quiescent current is negligible. Excessive power dissipation will trigger the thermal protection circuit.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS76801QD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	76801
TPS76801QD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76801
TPS76801QDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 125	76801
TPS76801QDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76801
TPS76801QDRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76801
TPS76801QPWP	Active	Production	HTSSOP (PWP) 20	70 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76801
TPS76801QPWP.A	Active	Production	HTSSOP (PWP) 20	70 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76801
TPS76801QPWPG4	Active	Production	HTSSOP (PWP) 20	70 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76801
TPS76801QPWPR	Active	Production	HTSSOP (PWP) 20	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76801
TPS76801QPWPR.A	Active	Production	HTSSOP (PWP) 20	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76801
TPS76801QPWPRG4	Active	Production	HTSSOP (PWP) 20	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76801
TPS76815QD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76815
TPS76815QD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76815
TPS76815QDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76815
TPS76815QDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76815
TPS76815QPWP	Active	Production	HTSSOP (PWP) 20	70 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76815
TPS76815QPWP.A	Active	Production	HTSSOP (PWP) 20	70 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76815
TPS76815QPWPR	Active	Production	HTSSOP (PWP) 20	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76815
TPS76815QPWPR.A	Active	Production	HTSSOP (PWP) 20	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76815
TPS76818QD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76818
TPS76818QD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76818
TPS76818QDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76818
TPS76818QDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76818
TPS76818QPWP	Active	Production	HTSSOP (PWP) 20	70 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76818
TPS76818QPWP.A	Active	Production	HTSSOP (PWP) 20	70 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76818
TPS76818QPWPR	Active	Production	HTSSOP (PWP) 20	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76818
TPS76818QPWPR.A	Active	Production	HTSSOP (PWP) 20	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76818
TPS76825QD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76825
TPS76825QD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76825

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS76825QDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76825
TPS76825QDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76825
TPS76825QPWP	Active	Production	HTSSOP (PWP) 20	70 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76825
TPS76825QPWP.A	Active	Production	HTSSOP (PWP) 20	70 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76825
TPS76825QPWPR	Active	Production	HTSSOP (PWP) 20	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76825
TPS76825QPWPR.A	Active	Production	HTSSOP (PWP) 20	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76825
TPS76827QD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76827
TPS76827QD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76827
TPS76828QD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76828
TPS76828QD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76828
TPS76830QD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76830
TPS76830QD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76830
TPS76830QPWP	Active	Production	HTSSOP (PWP) 20	70 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76830
TPS76830QPWP.A	Active	Production	HTSSOP (PWP) 20	70 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76830
TPS76833QD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76833
TPS76833QD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76833
TPS76833QDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76833
TPS76833QDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76833
TPS76833QPWP	Active	Production	HTSSOP (PWP) 20	70 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76833
TPS76833QPWP.A	Active	Production	HTSSOP (PWP) 20	70 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76833
TPS76833QPWPG4	Active	Production	HTSSOP (PWP) 20	70 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76833
TPS76833QPWPR	Active	Production	HTSSOP (PWP) 20	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76833
TPS76833QPWPR.A	Active	Production	HTSSOP (PWP) 20	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76833
TPS76833QPWPRG4	Active	Production	HTSSOP (PWP) 20	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76833
TPS76850QD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76850
TPS76850QD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76850
TPS76850QDG4	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76850
TPS76850QDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76850
TPS76850QDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	76850
TPS76850QPWP	Active	Production	HTSSOP (PWP) 20	70 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76850
TPS76850QPWP.A	Active	Production	HTSSOP (PWP) 20	70 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76850

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS76850QPWPR	Active	Production	HTSSOP (PWP) 20	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76850
TPS76850QPWPR.A	Active	Production	HTSSOP (PWP) 20	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	PT76850

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TPS768 :

- Automotive : [TPS768-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS76801QDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS76801QPWPR	HTSSOP	PWP	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TPS76815QDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS76815QPWPR	HTSSOP	PWP	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TPS76818QDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS76818QPWPR	HTSSOP	PWP	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TPS76825QDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS76825QPWPR	HTSSOP	PWP	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TPS76833QDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS76833QPWPR	HTSSOP	PWP	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TPS76850QDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS76850QPWPR	HTSSOP	PWP	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS76801QDR	SOIC	D	8	2500	353.0	353.0	32.0
TPS76801QPWPR	HTSSOP	PWP	20	2000	350.0	350.0	43.0
TPS76815QDR	SOIC	D	8	2500	350.0	350.0	43.0
TPS76815QPWPR	HTSSOP	PWP	20	2000	350.0	350.0	43.0
TPS76818QDR	SOIC	D	8	2500	350.0	350.0	43.0
TPS76818QPWPR	HTSSOP	PWP	20	2000	350.0	350.0	43.0
TPS76825QDR	SOIC	D	8	2500	350.0	350.0	43.0
TPS76825QPWPR	HTSSOP	PWP	20	2000	350.0	350.0	43.0
TPS76833QDR	SOIC	D	8	2500	350.0	350.0	43.0
TPS76833QPWPR	HTSSOP	PWP	20	2000	350.0	350.0	43.0
TPS76850QDR	SOIC	D	8	2500	350.0	350.0	43.0
TPS76850QPWPR	HTSSOP	PWP	20	2000	350.0	350.0	43.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TPS76801QD	D	SOIC	8	75	506.6	8	3940	4.32
TPS76801QD	D	SOIC	8	75	505.46	6.76	3810	4
TPS76801QD.A	D	SOIC	8	75	505.46	6.76	3810	4
TPS76801QD.A	D	SOIC	8	75	506.6	8	3940	4.32
TPS76801QPWP	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TPS76801QPWP.A	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TPS76801QPWPG4	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TPS76815QD	D	SOIC	8	75	505.46	6.76	3810	4
TPS76815QD.A	D	SOIC	8	75	505.46	6.76	3810	4
TPS76815QPWP	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TPS76815QPWP.A	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TPS76818QD	D	SOIC	8	75	505.46	6.76	3810	4
TPS76818QD.A	D	SOIC	8	75	505.46	6.76	3810	4
TPS76818QPWP	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TPS76818QPWP.A	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TPS76825QD	D	SOIC	8	75	505.46	6.76	3810	4
TPS76825QD.A	D	SOIC	8	75	505.46	6.76	3810	4
TPS76825QPWP	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TPS76825QPWP.A	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TPS76827QD	D	SOIC	8	75	505.46	6.76	3810	4
TPS76827QD.A	D	SOIC	8	75	505.46	6.76	3810	4
TPS76828QD	D	SOIC	8	75	505.46	6.76	3810	4
TPS76828QD.A	D	SOIC	8	75	505.46	6.76	3810	4
TPS76830QD	D	SOIC	8	75	505.46	6.76	3810	4
TPS76830QD.A	D	SOIC	8	75	505.46	6.76	3810	4
TPS76830QPWP	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TPS76830QPWP.A	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TPS76833QD	D	SOIC	8	75	505.46	6.76	3810	4
TPS76833QD.A	D	SOIC	8	75	505.46	6.76	3810	4

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TPS76833QPWP	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TPS76833QPWP.A	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TPS76833QPWPG4	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TPS76850QD	D	SOIC	8	75	505.46	6.76	3810	4
TPS76850QD.A	D	SOIC	8	75	505.46	6.76	3810	4
TPS76850QDG4	D	SOIC	8	75	505.46	6.76	3810	4
TPS76850QPWP	PWP	HTSSOP	20	70	530	10.2	3600	3.5
TPS76850QPWP.A	PWP	HTSSOP	20	70	530	10.2	3600	3.5

GENERIC PACKAGE VIEW

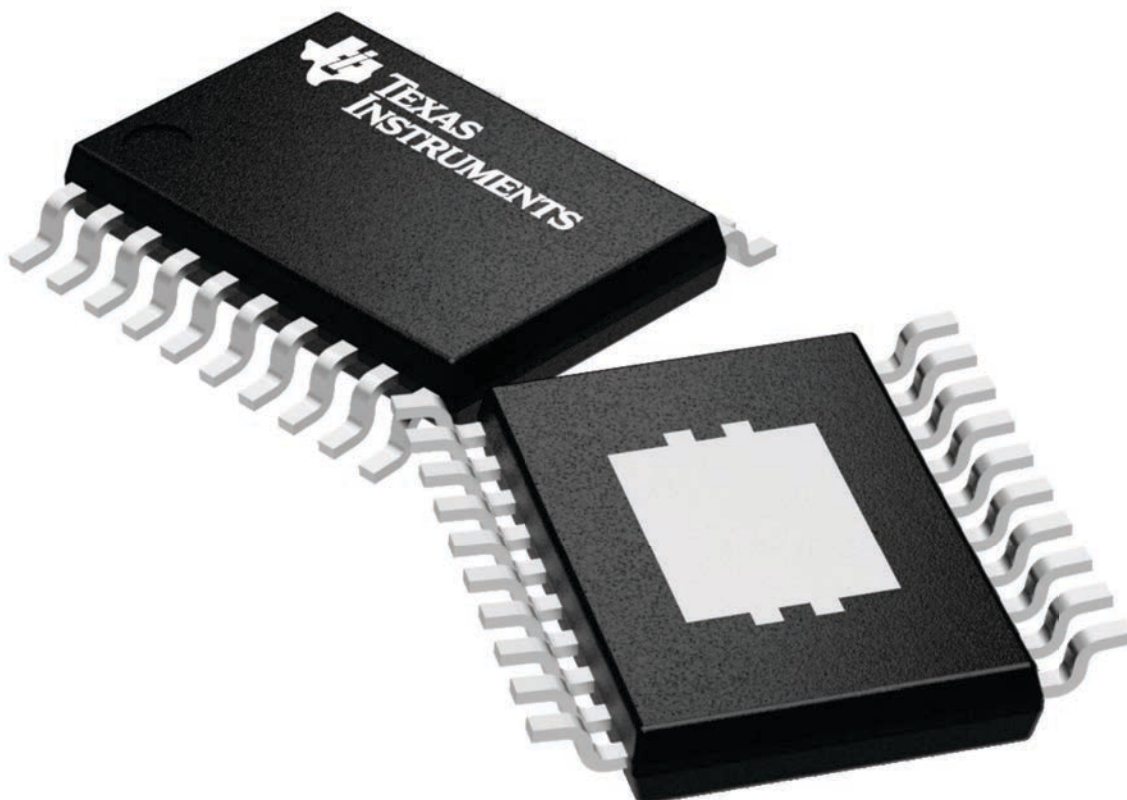
PWP 20

HTSSOP - 1.2 mm max height

6.5 x 4.4, 0.65 mm pitch

SMALL OUTLINE PACKAGE

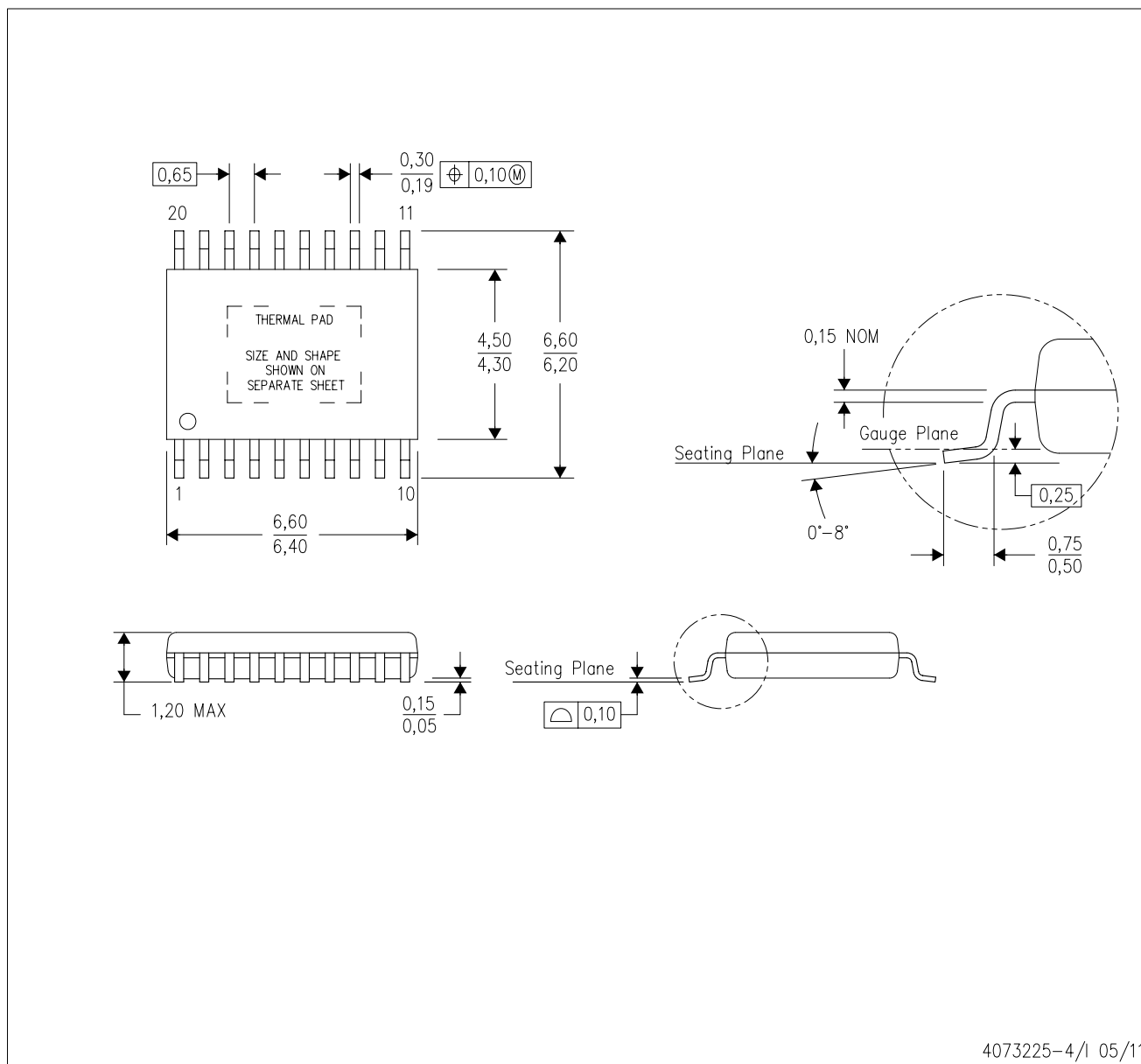
This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4224669/A

PWP (R-PDSO-G20)

PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
- This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <<http://www.ti.com>>.
- See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Falls within JEDEC MO-153

PowerPAD is a trademark of Texas Instruments.

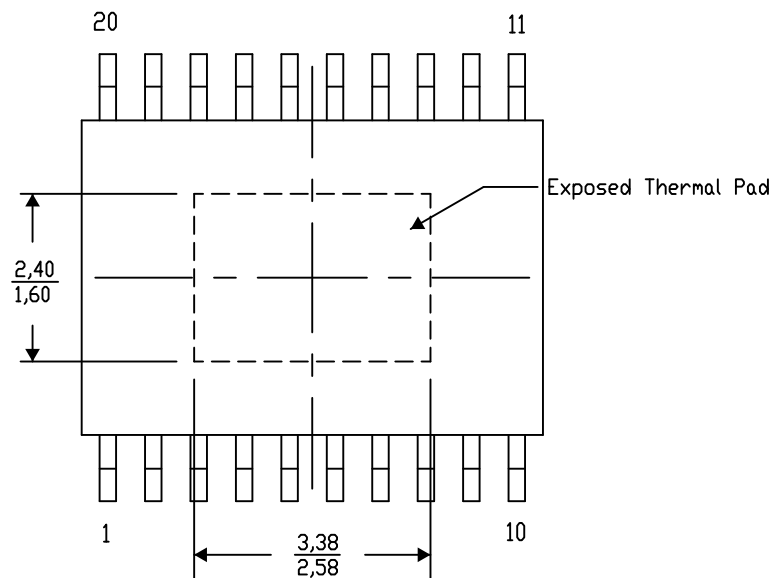
PWP (R-PDSO-G20) PowerPAD™ SMALL PLASTIC OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Top View

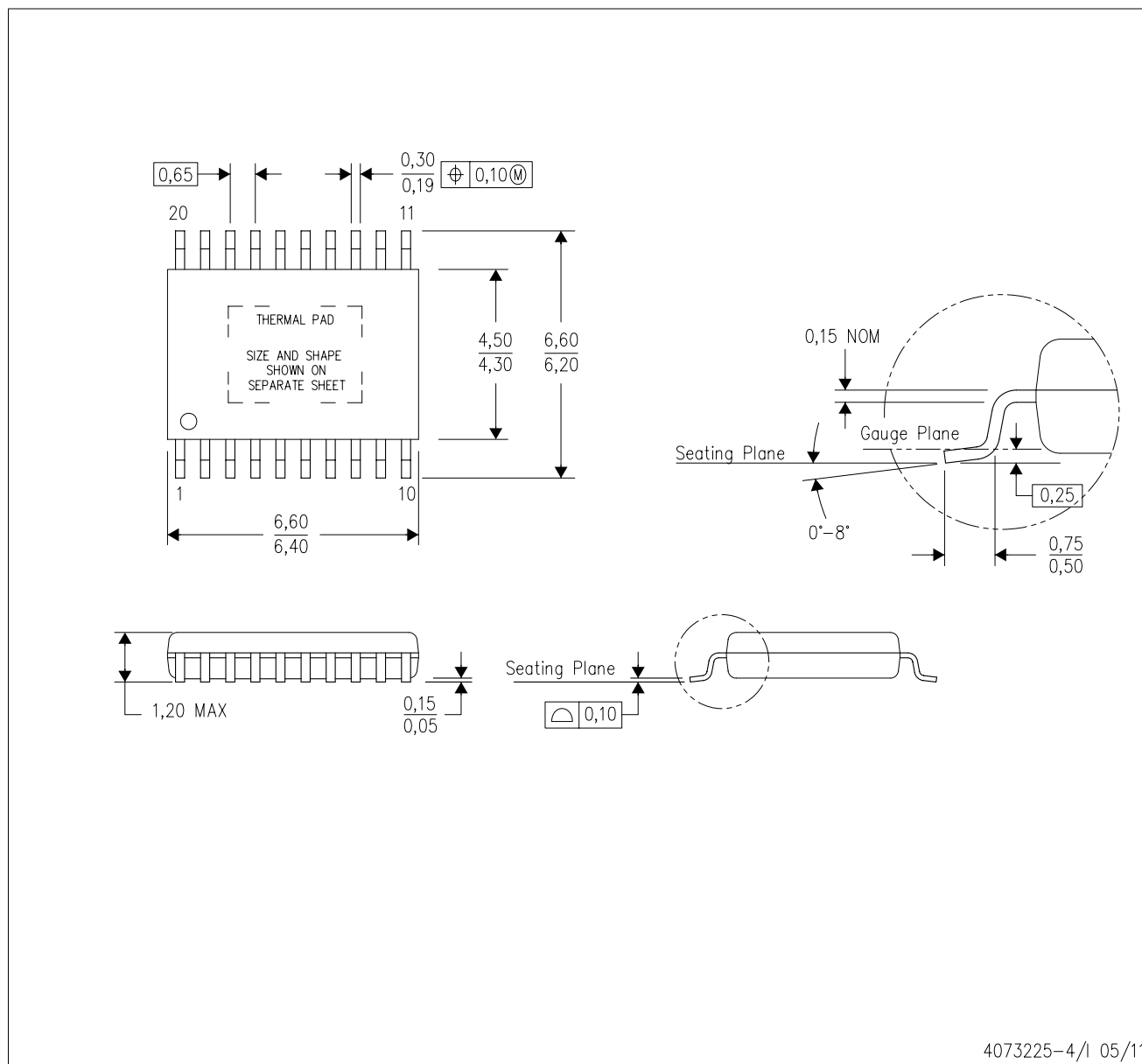
Exposed Thermal Pad Dimensions

4206332-21/AO 01/16

NOTE: A. All linear dimensions are in millimeters

PWP (R-PDSO-G20)

PowerPAD™ PLASTIC SMALL OUTLINE



4073225-4/1 05/11

- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
 - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <<http://www.ti.com>>.
 - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - Falls within JEDEC MO-153

PowerPAD is a trademark of Texas Instruments.

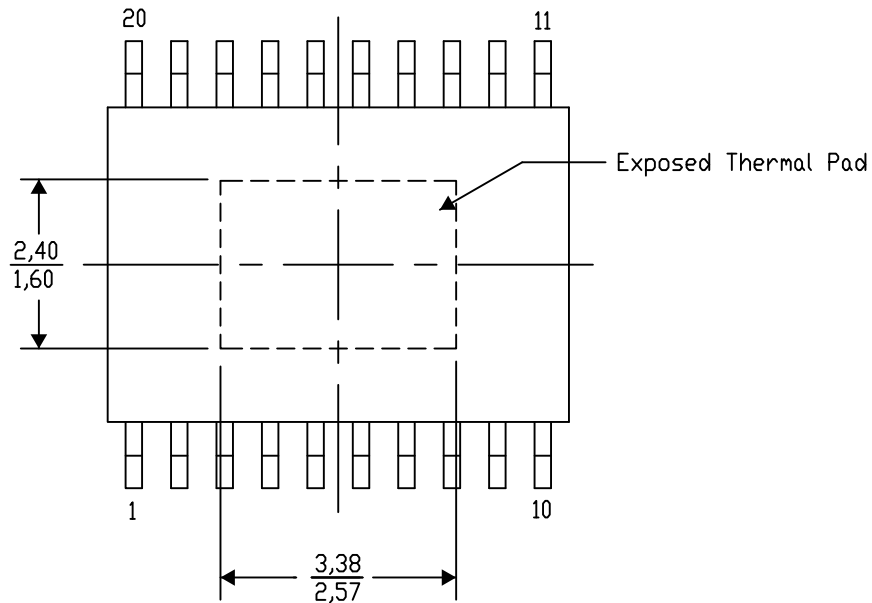
PWP (R-PDSO-G20) PowerPAD™ SMALL PLASTIC OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



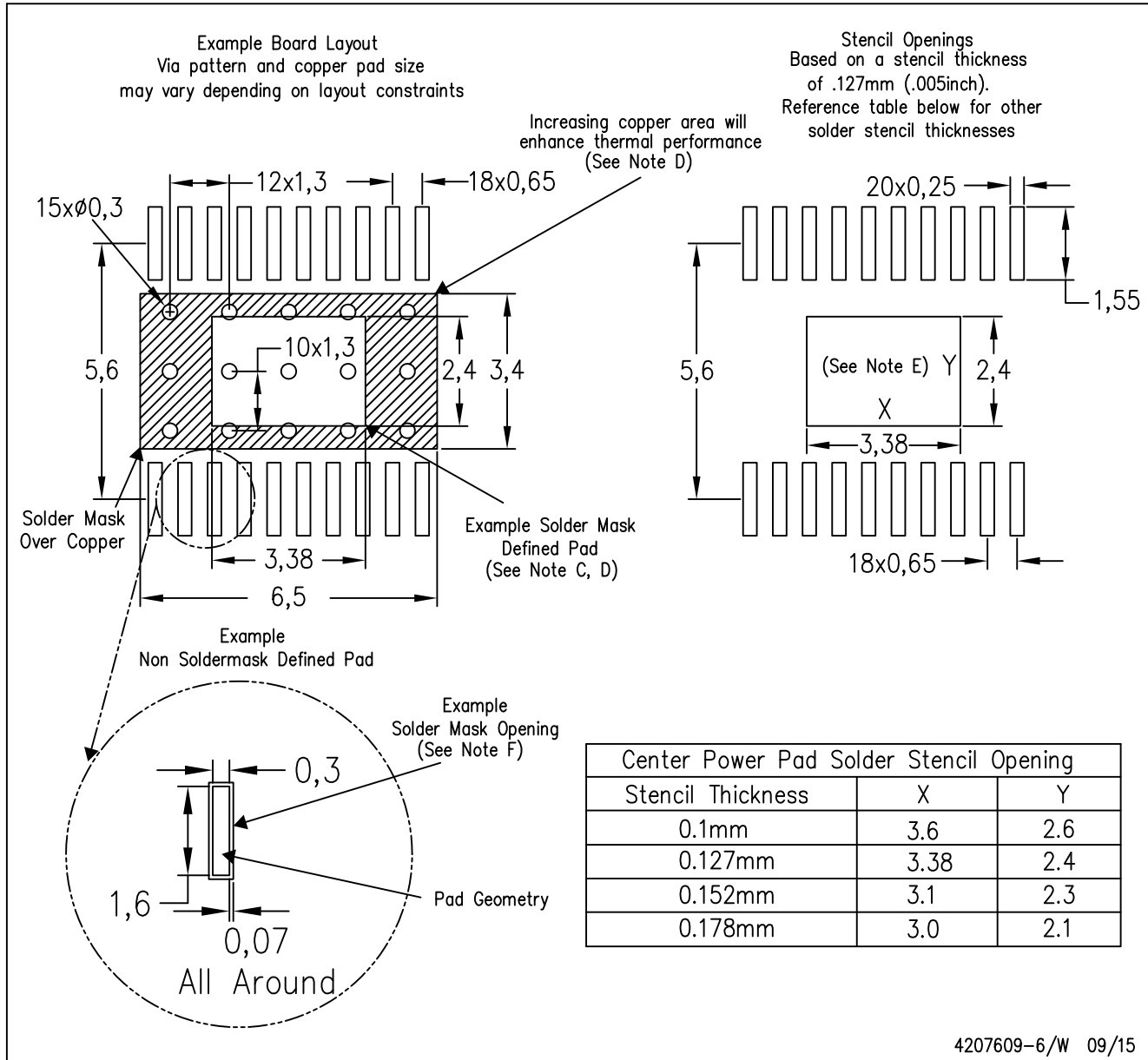
4206332-13/AO 01/16

NOTE: A. All linear dimensions are in millimeters

PowerPAD is a trademark of Texas Instruments

PWP (R-PDSO-G20)

PowerPAD™ PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <<http://www.ti.com>>. Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

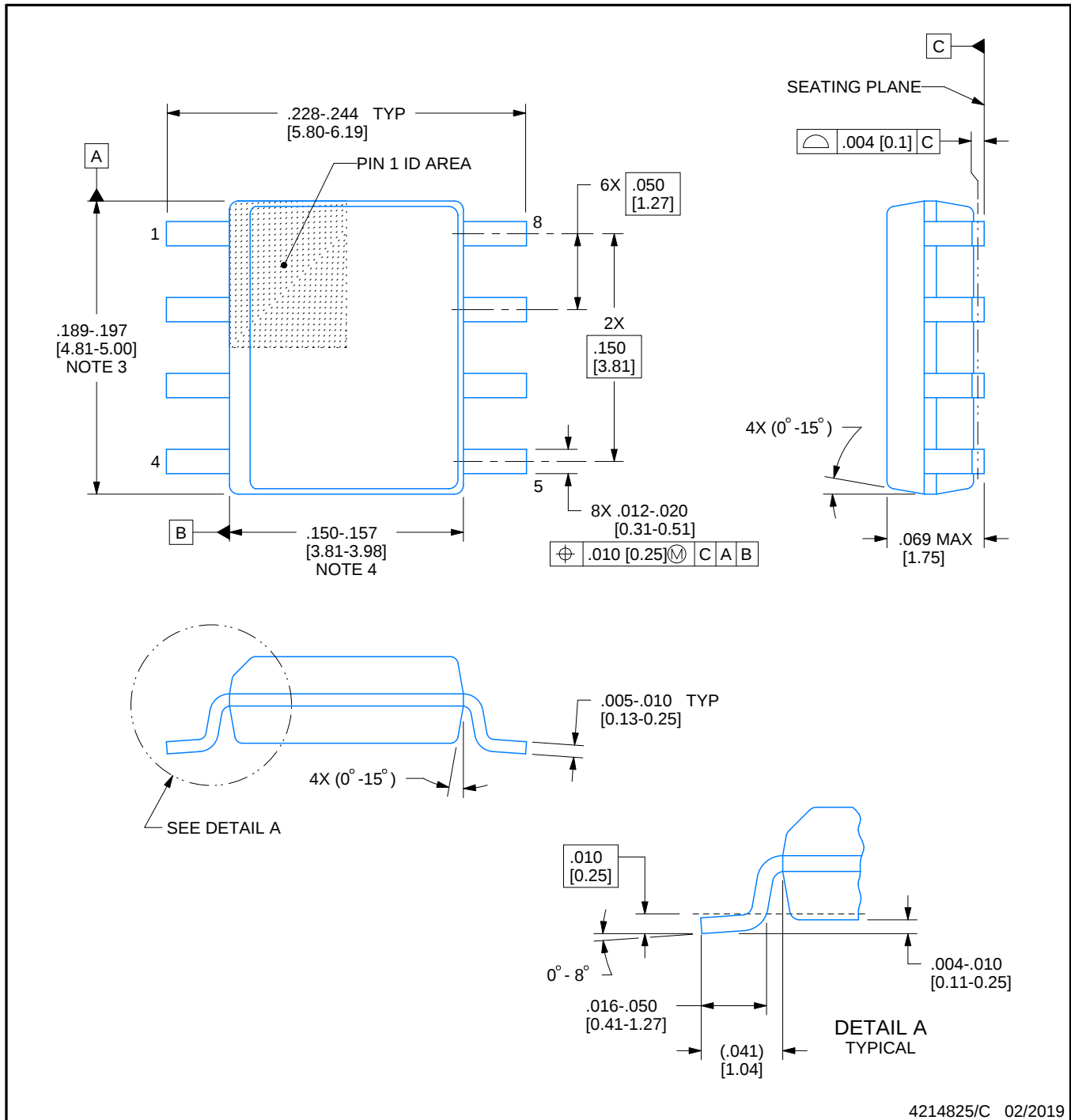


D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](https://www.ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2025, Texas Instruments Incorporated